

Silicon Bidirectional Switches

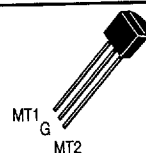
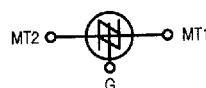
Diode Thyristors

... designed for full-wave triggering in Triac phase control circuits, half-wave SCR triggering application and as voltage level detectors. Supplied in an inexpensive plastic TO-226AA package for high-volume requirements, this low-cost plastic package is readily adaptable for use in automatic insertion equipment.

- Low Switching Voltage — 8 Volts Typical
- Uniform Characteristics in Each Direction
- Low On-State Voltage — 1.7 Volts Maximum
- Low Off-State Current — 0.1 μ A Maximum
- Low Temperature Coefficient — 0.02 %/ $^{\circ}$ C Typical

MBS4991
MBS4992
MBS4993

SBS
(PLASTIC)



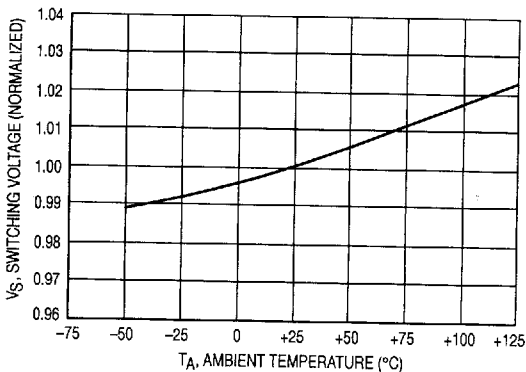
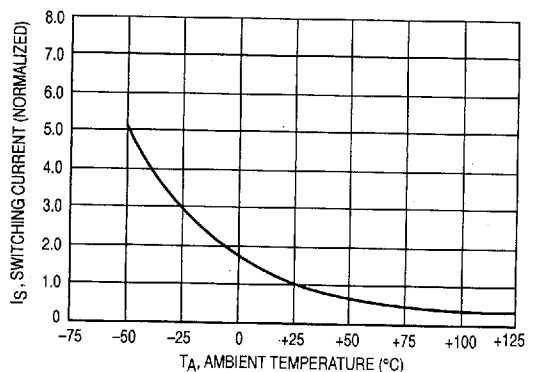
CASE 29-04
(TO-226AA)
STYLE 12

MAXIMUM RATINGS ($T_J = 25^{\circ}$ C unless otherwise noted.)

Rating	Symbol	Value	Unit
Power Dissipation	P_D	500	mW
DC Forward Current	I_F	200	mA
DC Gate Current (Off-State Only)	$I_{G(off)}$	5	mA
Repetitive Peak Forward Current (1% Duty Cycle, 10 μ s Pulse Width, $T_A = 100^{\circ}$ C)	$I_{FM(rep)}$	2	Amps
Non-repetitive Forward Current (10 μ s Pulse Width, $T_A = 25^{\circ}$ C)	$I_{FM(nonrep)}$	6	Amps
Operating Junction Temperature Range	T_J	-55 to +125	$^{\circ}$ C
Storage Temperature Range	T_{stg}	-65 to +150	$^{\circ}$ C

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted.)

Characteristic		Symbol	Min	Typ	Max	Unit
Switching Voltage	MBS4991 MBS4992, MBS4993	V_S	6 7.5	8 8	10 9	Vdc
Switching Current	MBS4991 MBS4992 MBS4993	I_S	— —	175 90 175	500 120 250	μAdc
Switching Voltage Differential (See Figure 10)	MBS4991 MBS4992, MBS4993	$ V_{S1}-V_{S2} $	— —	0.3 0.1	0.5 0.2	Vdc
Gate Trigger Current ($V_F = 5\text{ Vdc}$, $R_L = 1\text{ k ohm}$)	MBS4992 MBS4993	I_{GF}	— —	— —	100 500	μAdc
Holding Current	MBS4991 MBS4992 MBS4993	I_H	— — —	0.7 0.2 0.3	1.5 0.5 0.75	mAdc
Off-State Blocking Current ($V_F = 5\text{ Vdc}$, $T_A = 25^\circ\text{C}$) ($V_F = 5\text{ Vdc}$, $T_A = 85^\circ\text{C}$) ($V_F = 5\text{ Vdc}$, $T_A = 25^\circ\text{C}$) ($V_F = 5\text{ Vdc}$, $T_A = 100^\circ\text{C}$)	MBS4991 MBS4991 MBS4992, MBS4993 MBS4992, MBS4993	I_B	— — — —	0.08 2 0.08 6	1 10 0.1 10	μAdc
Forward On-State Voltage ($I_F = 175\text{ mAdc}$) ($I_F = 200\text{ mAdc}$)	MBS4991 MBS4992, MBS4993	V_F	— —	1.4 1.5	1.7 1.7	Vdc
Peak Output Voltage ($C_C = 0.1\text{ }\mu\text{F}$, $R_L = 20\text{ ohms}$, (Figure 7))		V_O	3.5	4.8	—	Vdc
Turn-On Time (Figure 8)		t_{on}	—	1	—	μs
Turn-Off Time (Figure 9)		t_{off}	—	30	—	μs
Temperature Coefficient of Switching Voltage (-50 to $+125^\circ\text{C}$)		T_C	—	+0.02	—	$\%/^\circ\text{C}$
Switching Current Differential (See Figure 10)		$I_{S1}-I_{S2}$	—	—	100	μA

TYPICAL ELECTRICAL CHARACTERISTICS
FIGURE 1 – SWITCHING VOLTAGE versus TEMPERATURE

FIGURE 2 – SWITCHING CURRENT versus TEMPERATURE


MBS4991 MBS4992 MBS4993

FIGURE 3 – HOLDING CURRENT versus TEMPERATURE

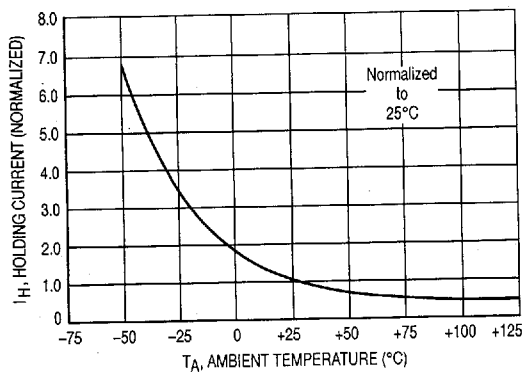


FIGURE 4 – OFF-STATE BLOCKING CURRENT versus TEMPERATURE

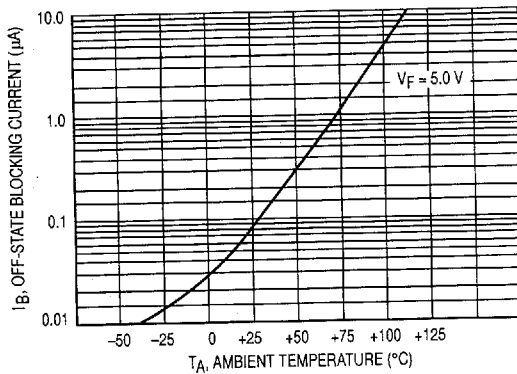


FIGURE 5 – ON-STATE VOLTAGE versus FORWARD CURRENT

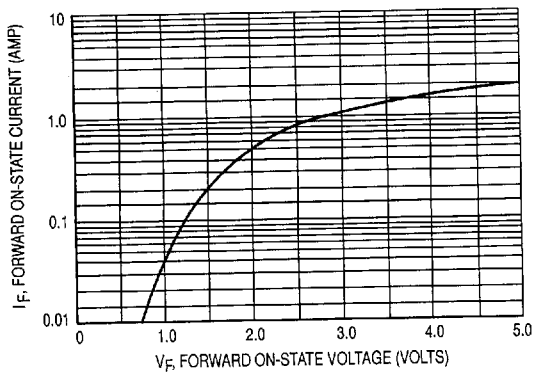


FIGURE 6 – PEAK OUTPUT VOLTAGE (FUNCTION OF R_L AND C_C)

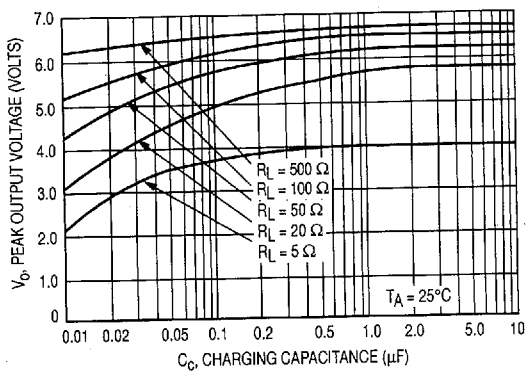


FIGURE 7 – PEAK OUTPUT VOLTAGE TEST CIRCUIT

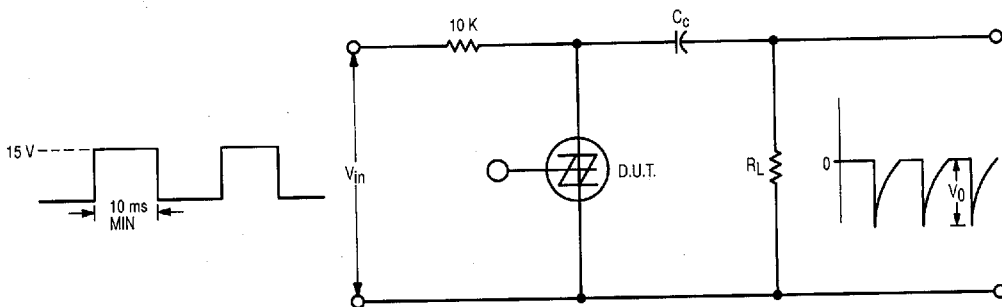
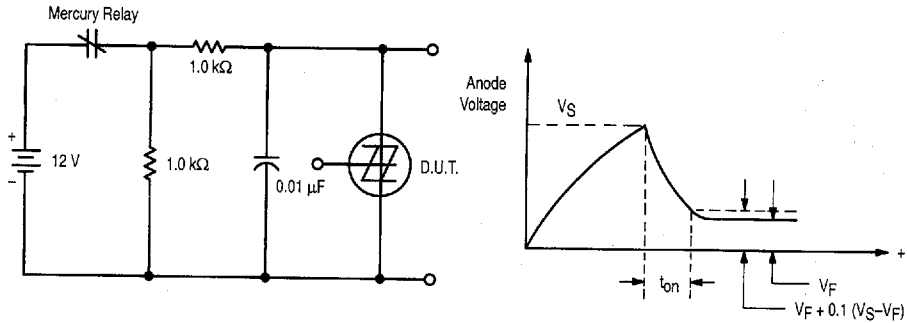
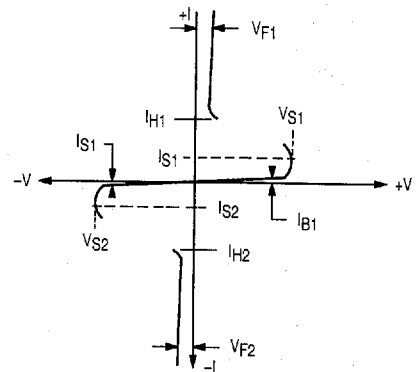
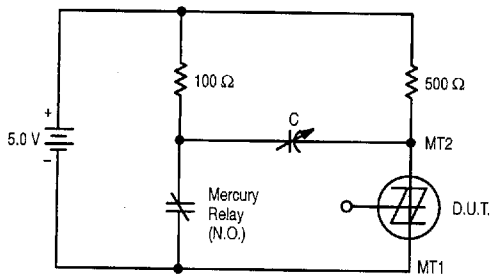


FIGURE 8 – TURN-ON TIME TEST CIRCUIT



Turn-on time is measured from the time V_S is achieved to the time when the anode voltage drops to within 90% of the difference between V_S and V_F .

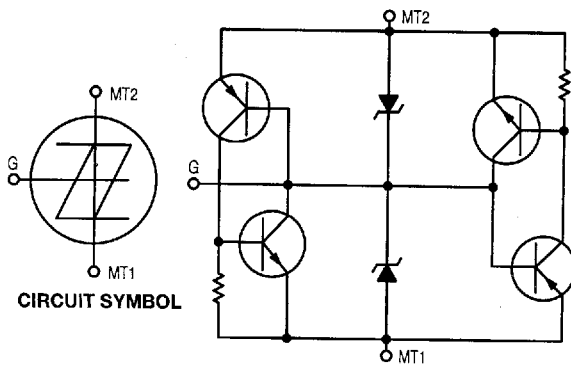
FIGURE 9 – TURN-OFF TIME TEST CIRCUIT



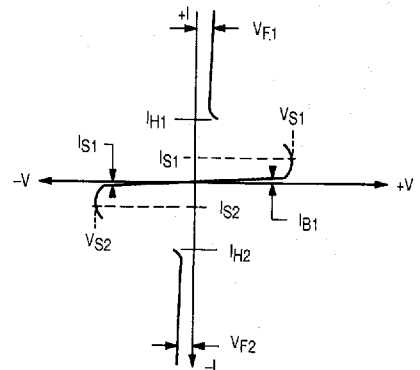
CHARACTERISTICS

With the SBS in conduction and the relay contacts open, close the contacts to cause anode A2 to be driven negative. Decrease C until the SBS just remains off when anode A2 becomes positive. The turn off time, t_{off} , is the time from initial contact closure and until anode A2 voltage reaches zero volts.

FIGURE 10 – DEVICE EQUIVALENT CIRCUIT, CHARACTERISTICS AND SYMBOLS



EQUIVALENT CIRCUIT



CHARACTERISTICS